








	<h2>SI7852DP-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI7852DP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 80V 7.6A PPAK SO-8</p> <p>Datenblätter:  SI7852DP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 10438 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7852DP-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 80V 7.6A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	10438 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	1.9W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	80V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7.6A (Ta)
Rds On (Max) @ Id, Vgs	16.5 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2V @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	41nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)









































SI7852DP-T1-GE3 ist neu im Original, Suche SI7852DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7852DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7852DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI7852DP-T1 VISHAY SI7852DP-T1 VISHAY	 SI7852DP VISHAY SI7852DP VISHAY	 SI7856ADP-T1 Vishay Precision Group SI7856ADP-T1 VISHAY	 SI7856ADP-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 15A PPAK SO-8
 SI7852DP-T1-E3 Vishay / Siliconix MOSFET N-CH 80V 7.6A PPAK SO-8	 SI7852DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 80V 7.6A PPAK SO-8	 SI7856ADP SI SI7856ADP SI	 SI7852DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 80V 7.6A PPAK SO-8

heiße Teile

Mehr

 SI7846DP-T1-GE3	 SI7846DP-T1	 SI7846SAC	 SI7848BDP-T1-E3	 SI7848BDP-T1-E3
 SI7848BDP-T1-GE3	 SI7848BDP-T1-GE3	 SI7848DP	 SI7848DP-T1-E3	 SI7848DP-T1-E3
 SI7848DP-T1-GE3	 SI7850DP	 SI7850DP-T1-E3	 SI7850DP-T1-E3	 SI7850DP-T1-GE3
 SI7850DP-T1-GE3	 SI7852ADP	 SI7852ADP-T1-E3	 SI7852ADP-T1-E3	 SI7852ADP-T1-GE3
 SI7852ADP-T1-GE3	 SI7852DP	 SI7852DP-T1-E3	 SI7852DP-T1-E3	 SI7852DP-T1-GE3
 SI7856ADP	 SI7856ADP-T1-E3	 SI7856ADP-T1-E3	 SI7856ADP-T1-GE3	 SI7856ADP-T1-GE3
 SI7856DP-T1	 SI7856DP-T1-GE3	 SI7856DP-TI-E3	 SI7858ADP	 SI7858ADP-T1-E3
 SI7858ADP-T1-E3	 SI7858ADP-T1-GE3	 SI7858ADP-T1-GE3	 SI7858BDP	 SI7858BDP-T1-E3
 SI7860ADP	 SI7860ADP-T1-E3	 SI7860ADP-T1-E3	 SI7860ADP-T1-GE3	 SI7860ADP-T1-GE3
 SI7860ADP-TI-E3	 SI7860DP	 SI7860DP-T1	 SI7860DP-T1-E3	 SI7860DP-T1-E3

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